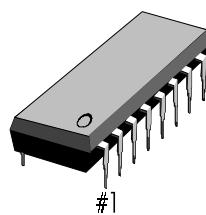


## INTRODUCTION

The KA22134 is a monolithic integrated circuit designed for use in low voltage and low power applications. It has various functions including those of a dual audio pre-power amplifier, DC volumecontrol and headphone drive circuits. It is suitable for portable tape recorders or headphone cassette recorders.

16-DIP-300A



#1

## FEATURES

- Built-in DC volume control circuit
- Wide operation supply voltage:  $V_{CC} = 1.8V \sim 6V$
- Only a few components needed to build headphone cassette tape recorders
- Built-in ripple filter

## ORDERING INFORMATION

Device	Package	Operating Temperature
KA22134	16-DIP-300A	-20°C ~ +75°C

## BLOCK DIAGRAM

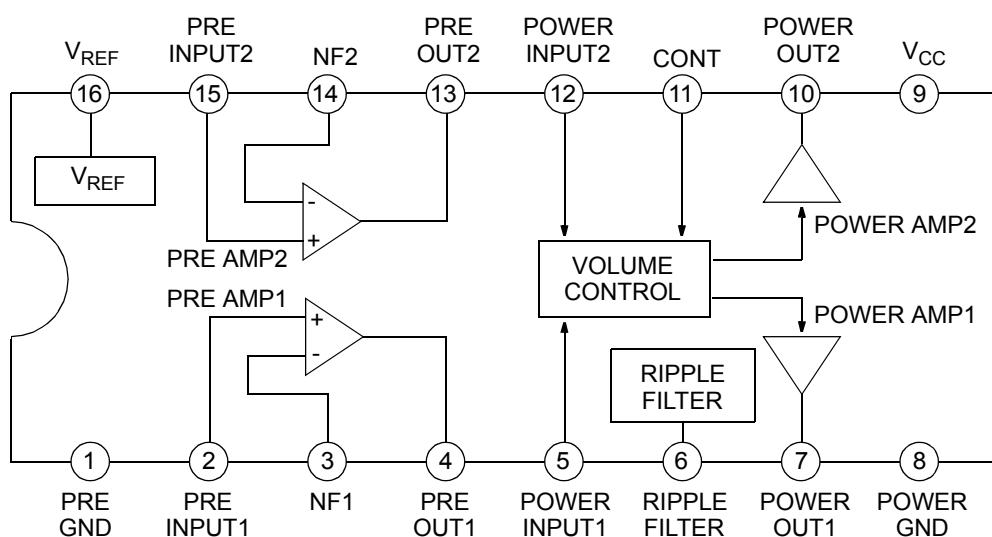


Figure 1.

**ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)**

<b>Characteristic</b>	<b>Symbol</b>	<b>Value</b>	<b>Unit</b>
Supply Voltage	V <sub>CC</sub>	7	V
Power Dissipation	P <sub>D</sub>	750	mW
Operating Temperature	T <sub>OPR</sub>	- 20 ~ +75	°C
Storage Temperature	T <sub>STG</sub>	- 40 ~ +125	°C

**ELECTRICAL CHARACTERISTICS**(V<sub>CC</sub> = 3V, Ta = 25°C, f = 1kHz, R<sub>L1</sub> = 10kΩ, unless otherwise specified)

<b>Characteristic</b>	<b>Symbol</b>	<b>Test Conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Quiescent Circuit Current	I <sub>CCQ1</sub>	V <sub>I</sub> = 0, V <sub>OL</sub> = MIN	—	9	13	mA
	I <sub>CCQ2</sub>	V <sub>I</sub> = 0, V <sub>OL</sub> = MAX	—	11	—	mA
Cross Talk	CT	R <sub>G</sub> = 2.2kΩ, V <sub>O</sub> = -10dBm	34	40	—	dB

**PRE-AMPLIFIER SECTION**(V<sub>CC</sub> = 3V, Ta = 25°C, f = 1kHz, R<sub>L1</sub> = 10kΩ, unless otherwise specified)

<b>Characteristic</b>	<b>Symbol</b>	<b>Test conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Open Loop Voltage Gain	G <sub>VO</sub>	V <sub>I</sub> = 0.2mV	55	62	—	dB
Closed Loop Voltage Gain	G <sub>VC1</sub>	V <sub>O</sub> = -10dBm, NAB 1kHz	—	33	—	dB
Output Voltage	V <sub>O</sub>	THD = 1%	600	720	—	mV
Total Harmonic Distortion	THD <sub>1</sub>	V <sub>O</sub> = -10dBm	—	0.04	0.1	%
Ripple Rejection Ratio	RR <sub>1</sub>	R <sub>G</sub> = 2.2kΩ V <sub>R</sub> = -20dBm, f <sub>R</sub> = 100Hz	—	46	—	dB
Equivalent Input Noise Voltage	V <sub>NI</sub>	R <sub>G</sub> = 2.2kΩ, BW = 30 ~ 20kHz Gain for NAB 1kHz	—	1.2	2.0	μV

**POWER AMPLIFIER SECTION**(V<sub>CC</sub> = 3V, Ta = 25°C, f = 1kHz, R<sub>L2</sub> = 32Ω, unless otherwise specified)

<b>Characteristic</b>	<b>Symbol</b>	<b>Test conditions</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
Output Power	P <sub>O1</sub>	THD2 = 10%	20	27	—	mW
	P <sub>O2</sub>	THD2 = 10%, RL = 16Ω	—	39	—	mW
Total Harmonic Distortion	THD <sub>2</sub>	P <sub>O</sub> = 10mW, Volume: 100%	—	0.5	1.2	%
	THD <sub>3</sub>	P <sub>O</sub> = 10mW, Volume: 50%	—	0.3	—	%
Closed Loop Voltage Gain	G <sub>VC2</sub>	V <sub>O</sub> = -0dBm, Volume: 100%	28	30	32	dB
	G <sub>VC3</sub>	V <sub>O</sub> = -10dBm, Volume: 50%	—	15	—	dB
Channel Balance	C <sub>B</sub>	V <sub>O</sub> = -10dBm	— 1.5	0	1.5	dB
Volume Rejection Ratio	VOL <sub>REJ</sub>	V <sub>O</sub> = -10dBm Volume: 100% to 0%	66	72	—	dB
Output Noise Voltage	V <sub>NO</sub>	BW = 30 ~ 20kHz, R <sub>G</sub> = 600Ω	—	250	320	µV
Ripple Rejection Ratio	RR <sub>2</sub>	R <sub>G</sub> = 600Ω, f <sub>r</sub> = 100Hz V <sub>r</sub> = -20dBm	—	46	—	dB

## TEST CIRCUIT

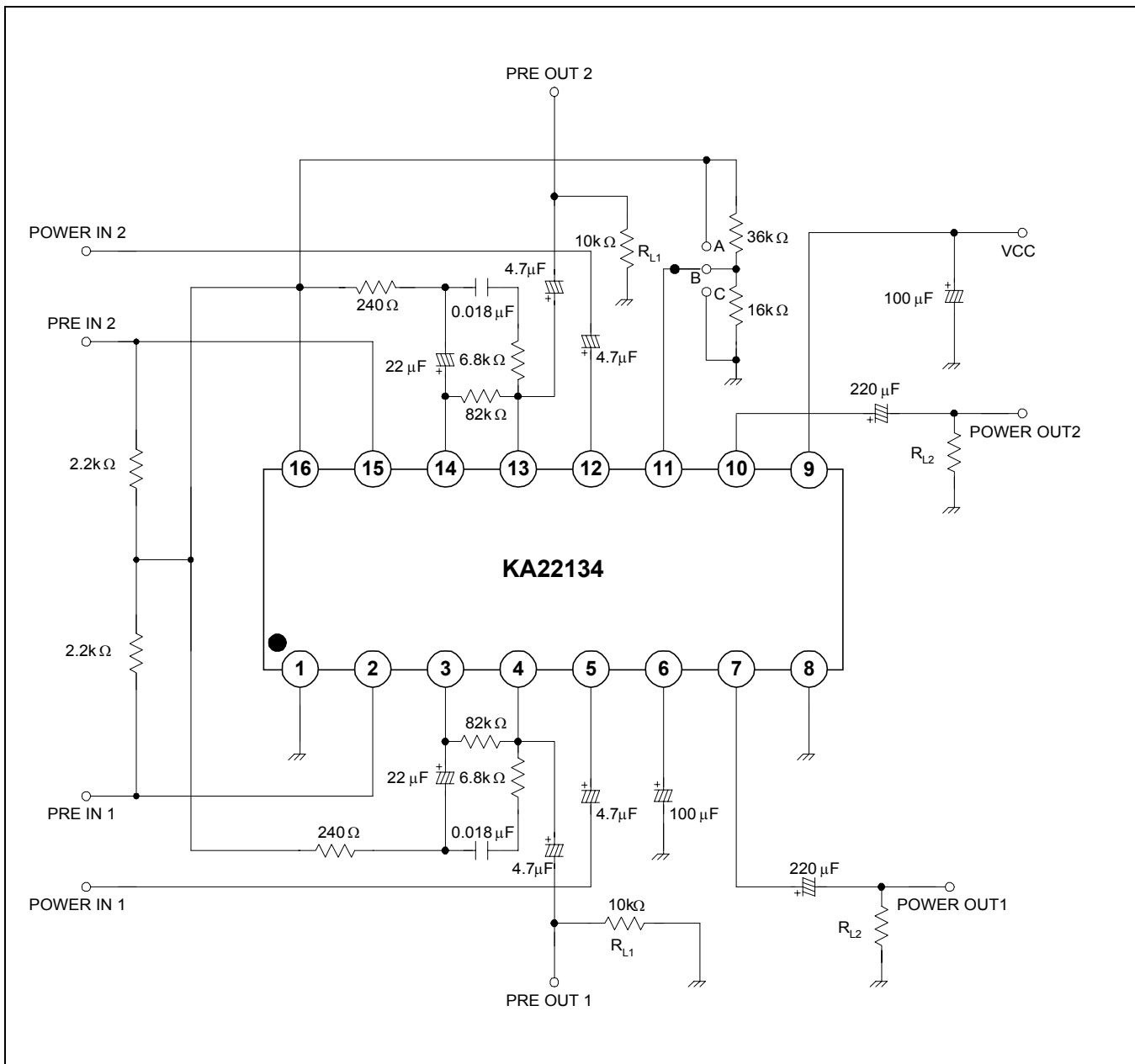


Figure 2.

## APPLICATION CIRCUIT

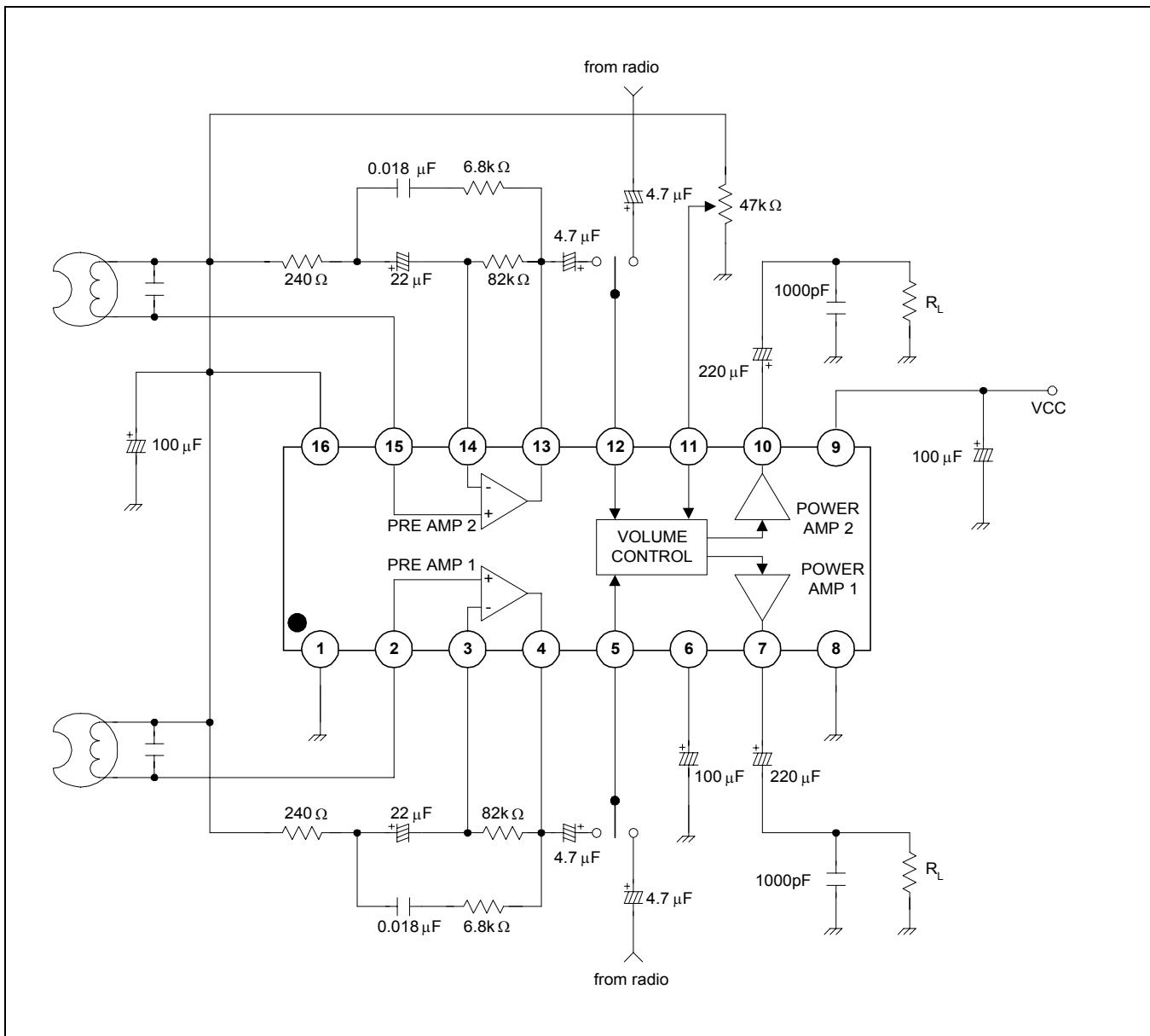


Figure 3.

**NOTES**